

# isc N-Channel MOSFET Transistor

# APT30M36LLL

#### **FEATURES**

- Drain Current -I<sub>D</sub>= 84A@ T<sub>C</sub>=25 °C
- · Drain Source Voltage-
  - : V<sub>DSS</sub>=300V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 0.036 \Omega (Max)$
- 100% avalanche tested
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **DESCRIPTION**

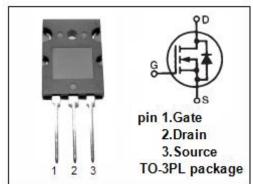
• Designed for use in switch mode power supplies and general purpose applications.

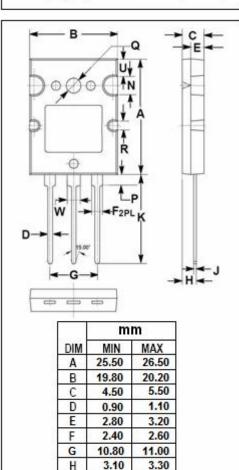
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
$V_{ extsf{DSS}}$	Drain-Source Voltage	300	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	-Continuous ±30	
Ι <sub>D</sub>	Drain Current-Continuous	84	А
I <sub>DM</sub>	Drain Current-Single Pluse	336	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	568	W
TJ	Max. Operating Junction Temperature	-55~150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.22	°C/W





DIM	MIN	MAX
Α	25.50	26.50
В	19.80	20.20
C	4.50	5.50
D	0.90	1.10
E	2.80	3.20
F	2.40	2.60
G	10.80	11.00
Н	3.10	3.30
J	0.50	0.70
K	20.00	21.00
N	3.90	4.50
Р	2.40	2.60
Q	3.10	3.50
R	1.90	2.60
U	3.90	4.10
W	2.90	3.25



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	300		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 2.5mA	3	5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =42A		0.036	Ω
Igss	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 300V; V <sub>GS</sub> = 0 V <sub>DS</sub> = 240V; V <sub>GS</sub> = 0@T <sub>C</sub> =125°C		100 500	μА
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> =-84A; V <sub>GS</sub> = 0		1.3	V

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